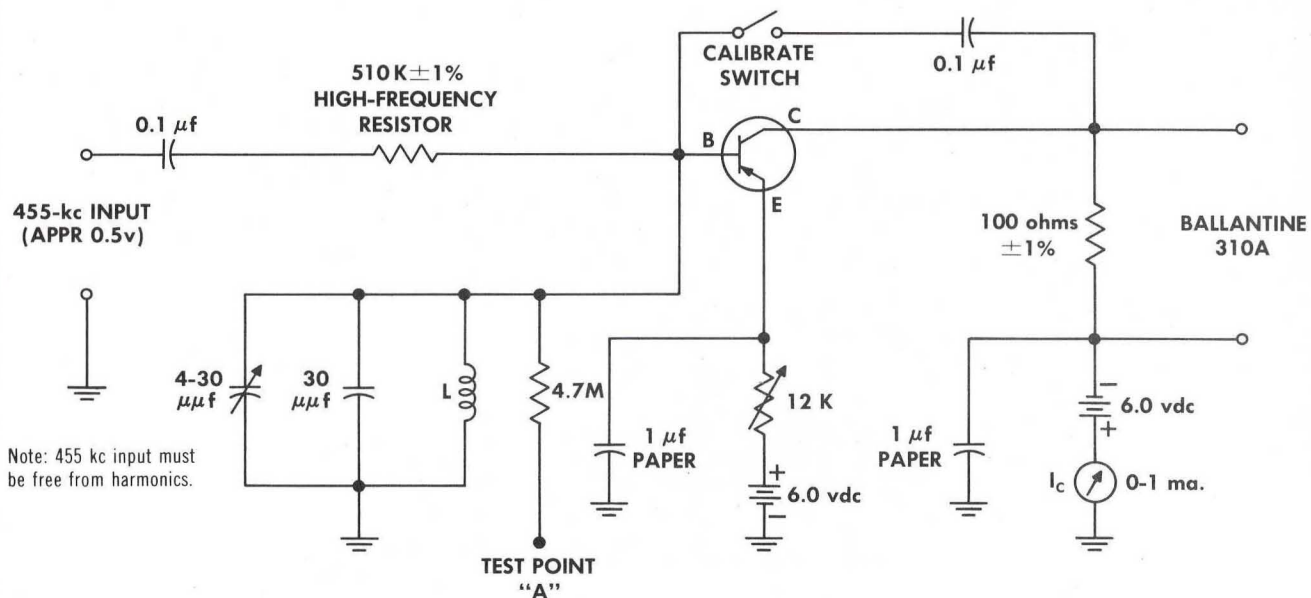


TYPE 2N1109

TEST CIRCUIT

455 - kc h_{fe} TEST SET



Coil Data

$L = 2.5$ mh

$Q = 150$ minimum at 455 kc

260 turns of #32 wire random wound on general ceramics

#F624-2 steatite Q_1 toroid core with one layer of insulated tape on bare core.

455-kc h_{fe} Test Set Operating Instructions

1. Connect a VTVM to test point "A" and adjust the 455-kc tuned circuit for resonance.
2. Close calibrate switch and adjust 455-kc input to give 0.1 mv reading on Ballantine 310A or equivalent.
3. Open calibrate switch, insert transistor, and set $I_C = 0.5$ ma.
4. Read h_{fe} value directly in db (0 db = 0.1 mv reference level).

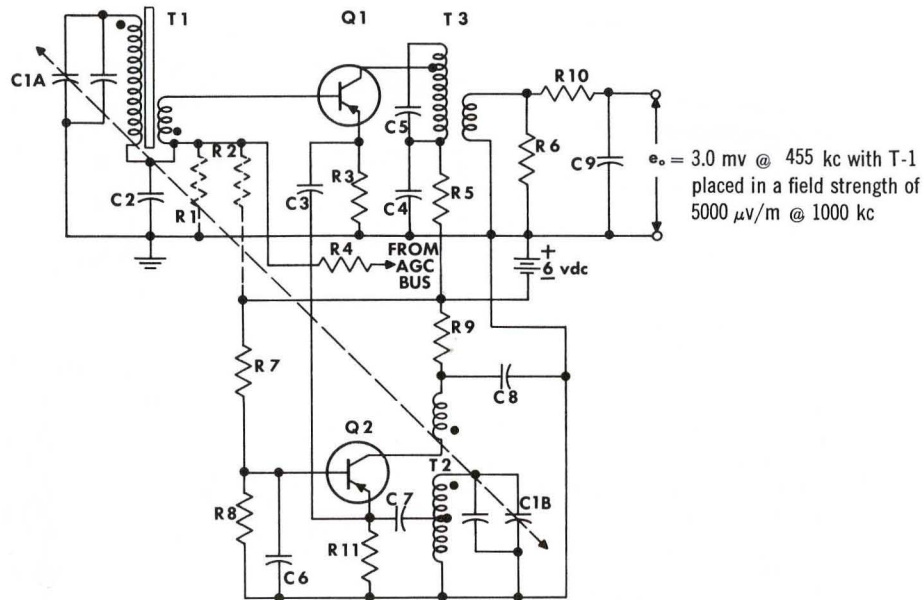
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TYPICAL OSCILLATOR—MIXER
(535 kc—1640 kc) TO 455 kc



$e_o = 3.0 \text{ mv @ } 455 \text{ kc with T-1}$
 $\text{placed in a field strength of}$
 $5000 \mu\text{V/m @ } 1000 \text{ kc}$

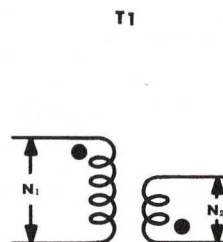
PARTS LIST:

- † R 1 = 6.8 K ohms
- † R 2 = 33 K ohms
- R 3, 11 = 3.3 K ohms
- R 4 = 10 K ohms
- R 5, 9 = 470 ohms
- * R 6, 10 = 4.7 K ohms
- R 7, 8 = 10 K ohms

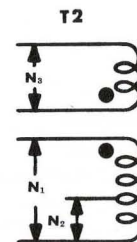
- C 1A = 12-138 $\mu\mu\text{f}$
- C 1B = 16.5-83 $\mu\mu\text{f}$
- C 2 = 0.005 μf
- C 3, 6 = 0.01 μf
- C 4, 7, 8 = 0.05 μf
- * C 9 = 100 $\mu\mu\text{f}$

- Q 1 = 2N1108
- Q 2 = 2N1109

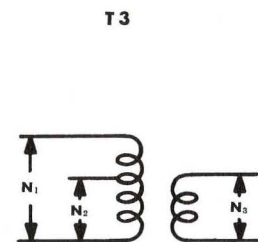
* Used for measurement of e_o only.
R 6 = 2.7 K for true loading.



L = 0.69 mh
Q_U = 360
Q_L = 50
N₁/N₂ = 5.0
Bar size:
4 5/8" x 3/4" x 1/8"
Material: Ferrite
C_{dist.} = 2.4 $\mu\mu\text{f}$
K = 0.64

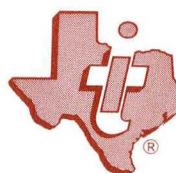


N₁ = 120T L₁ = 0.3 mh
N₂ = 2T Gears = 40/61
N₃ = 30T Cam = 0.156
Q_U = 90 Wire: 5-44 Litz
Coil Form: 0.285" dia.
Core Mat.: Powdered Iron
Universal Winding (1 pi)



Q_U = 65
Q_L = 50
N₁/N₂ = 3.1
N₁/N₃ = 14.6
Ins. Loss = 13 db

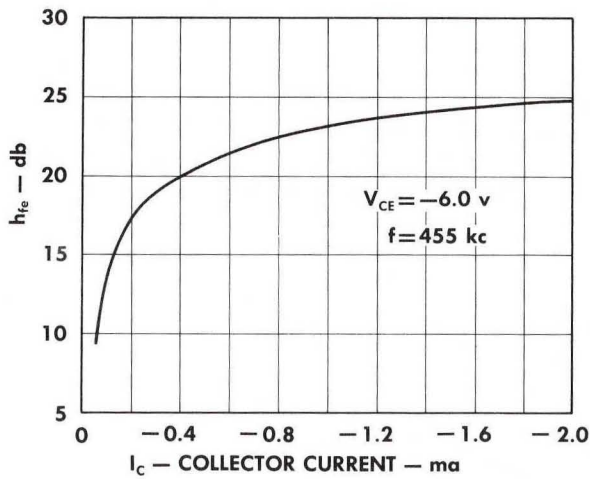
† To be used when AGC is not desired.



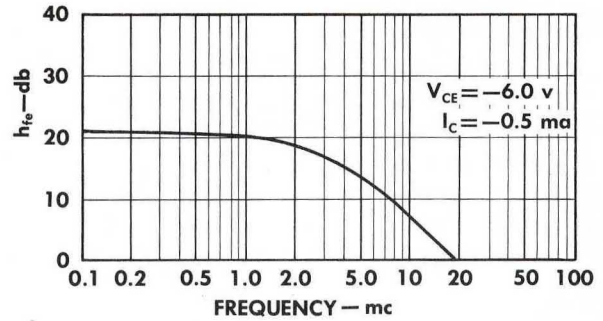
TYPE 2N1109

TYPICAL CHARACTERISTICS

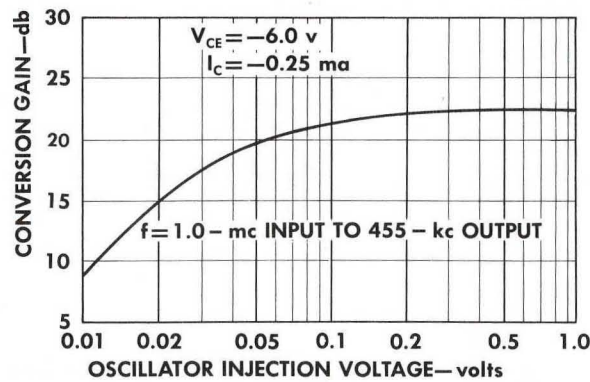
TYPICAL CURRENT AMPLIFICATION (h_{fe})
VS COLLECTOR CURRENT



TYPICAL CURRENT AMPLIFICATION (h_{fe})
VS FREQUENCY



TYPICAL CONVERSION GAIN
VS
OSCILLATOR INJECTION VOLTAGE



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